

AF/IFW

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

IN RE APPLICATION OF: KUO-CHIEN WU ET AL

SERIAL No.: 10/628,507

GROUP ART UNIT: 2822

FILED: July 29, 2003

EXAMINER: C. Novacek

FOR: METHOD FOR FORMING DRAM CELL BIT LINE
AND BIT LINE CONTACT STRUCTURE

ATTY. REFERENCE: WUKU3005/BEU

U.S. PATENT & TRADEMARK OFFICE
JAN 06 2005

COMMISSIONER OF PATENTS

P.O. Box 1450

Alexandria, VA 22313-1450

Sir:

Transmitted herewith is a communication/amendment in the above-identified application.

☐ Small entity status under 37 CFR 1.9 and 1.27 is claimed.

☒ No additional fee is required.

The fee, if any, has been calculated as shown below:

Fee Basis	Number of Claims After Amendment	Highest Number Previously Paid For	Extra Claims	Small Entity	Full Fee
Total Claims		¹	³	× \$ 25 =	× \$ 50 =
Independent Claims		²	³	× \$ 100 =	× \$ 200 =
<input type="checkbox"/> First Presentation of Proper Multiple Dependent Claim				+ \$ 180 =	+ \$ 360 =
TOTAL					

¹ If less than 20 enter 20.

² If less than 3 enter 3.

³ If less than 0 enter 0.

☐ Please charge my Deposit Account Number 02-0200 in the amount of \$. A duplicate copy of this sheet is attached.

☐ A check in the amount of \$ is attached.

☐ The Commissioner is hereby authorized to charge any additional fees associated with this communication, including fees due under 37 CFR 1.16 and 37 CFR 1.17 or credit any overpayment to Deposit Account Number 02-0200. A duplicate copy of this sheet is attached.

☐ Also enclosed is/are:

23364

Customer Number

Phone: (703) 683-0500

DATE: January 6, 2005

Respectfully submitted,



Benjamin E. Urcia

Attorney for Applicant

Registration Number: 33,805



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Response Under 37 CFR §1.116
EXPEDITED PROCEDURE

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re U.S. Patent Application of:)	<u>Group Art Unit:</u> 2822
)	
Kuo-Chien WU <i>et al.</i>)	<u>Examiner:</u> C. Novacek
)	
Serial Number: 10/628,507)	<u>Attorney Docket:</u> WUKU3005beu
)	
Filed: July 29, 2003)	<u>Confirmation No.:</u> 5047

For: Method For Forming DRAM Cell Bit Line And Bit Line Contact Structure

RESPONSE UNDER 37 CFR §1.116, AFTER FINAL

Honorable Commissioner For Patents
P.O. Box 1450
Alexandria, VA. 22313-1450

Sir:

This paper is in response to the Official Action dated April 2, 2004.

Amendments to the claims begin on page 2.

Remarks/Arguments begin on page 4.